The RF Line NPN Silicon High-Frequency Transistor

Designed primarily for use in low-power amplifiers to 1.0 GHz. Ideal for pagers and other battery operated systems where power consumption is critical.

Available in tape and reel packaging options:
 T1 suffix = 3,000 units per reel

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	VCEO	5.0	Vdc
Collector-Base Voltage	VCBO	10	Vdc
Emitter-Base Voltage	VEBO	2.0	Vdc
Collector Current — Continuous	IC	5.0	mAdc
Maximum Junction Temperature	T _{Jmax}	150	°C
Power Dissipation, T _{Case} = 75°C (1) Derate linearly above 75°C @	P _{D(max)}	0.150 2.00	W mW/°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Storage Temperature	T _{stg}	-55 to +150	°C
Thermal Resistance Junction to Case	$R_{\theta JC}$	500	°C/W

DEVICE MARKING

MMBR931LT1 = 7D

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage (I _C = 0.1 mAdc, I _B = 0)	V(BR)CEO	15	_	_	Vdc
Collector–Base Breakdown Voltage (I _C = 0.01 mAdc, I _E = 0)	V(BR)CBO	20	_	_	Vdc
Emitter-Base Breakdown Voltage (I _E = 0.1 mAdc, I _C = 0)	V(BR)EBO	3.5	_	_	Vdc
Collector Cutoff Current (V _{CB} = 5.0 Vdc, I _E = 0)	ICBO	_	_	50	nAdc
ON CHARACTERISTICS					
DC Current Gain (I _C = 0.25 mAdc, V _{CE} = 1.0 Vdc)	hFE	50	_	150	_
SMALL-SIGNAL CHARACTERISTICS					
Collector–Base Capacitance (V _{CB} = 1.0 Vdc, I _E = 0, f = 1.0 MHz)	C _{cb}	_	_	0.5	pF
Noise Figure (I _E = 0.25 mAdc, V _{CE} = 1.0 Vdc, f = 1.0 GHz)	NF	_	4.3	_	dB
Power Gain at Optimum Noise Figure (I _E = 0.25 mAdc, V _{CE} = 1.0 Vdc, f = 1.0 GHz)	G _{NF}	_	10	_	_

NOTE:

MMBR931LT1

RF AMPLIFIER TRANSISTOR NPN SILICON

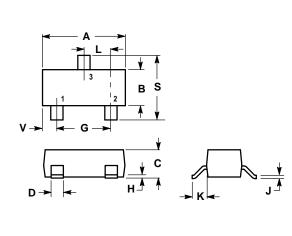


CASE 318–08, STYLE 6 SOT–23 LOW PROFILE (TO–236AA/AB)



^{1.} Case temperature measured on collector lead immediately adjacent to body of package.

PACKAGE DIMENSIONS



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
 Y14.5M. 1982.
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.
- MAXIUMUM LEAD THICKNESS INCLUDES
 LEAD FINISH THICKNESS. MINIMUM LEAD
 THICKNESS IS THE MINIMUM THICKNESS OF
 BASE MATERIAL.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.1102	0.1197	2.80	3.04	
В	0.0472	0.0551	1.20	1.40	
С	0.0350	0.0440	0.89	1.11	
D	0.0150	0.0200	0.37	0.50	
G	0.0701	0.0807	1.78	2.04	
Н	0.0005	0.0040	0.013	0.100	
J	0.0034	0.0070	0.085	0.177	
K	0.0140	0.0285	0.35	0.69	
L	0.0350	0.0401	0.89	1.02	
S	0.0830	0.1039	2.10	2.64	
٧	0.0177	0.0236	0.45	0.60	

STYLE 6: PIN 1. BASE

2. EMITTER 3. COLLECTOR

CASE 318-08 ISSUE AE

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